

EEE 454

VLSI I

Project Group No: 07

Project Title: VLSI Design Project: Configurable Logic Block (CLB)

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Date of Submission: 18.06.2021

INTRODUCTION

“Configurable Logic Block(CLB)” needs to be implemented in this project, more precisely 3:1 CLB. Three components of the CLB is listed below:

1. SRAM : 8 SRAM cells need to be implemented since this a 3: 1 CLB. These are memory cells. This memory array will store the input values of the mux of the LUT i.e output of our desired logic function.
2. LUT : It will perform 3 input NAND operation. A look up table is like a mux which will perform some specified logical operation to connect desired value stored in SRAM to the output.
3. D Flip-flop: Flip-flop will act like a memory element of the CLB block. It will enable the CLB to perform sequencing operation.
4. Mux : Mux will basically show outputs based on the input select pins. In this design 2:1 mux will be implemented.

“Configurable Logic Block(CLB)” design required following input & output pins :

1. LUT Input Pins : (2:0) Three select pins will be available as select pins of the mux placed inside the LUT block
2. Clk : This pin will be connected to the D flip-flop.
3. Load : This pin will control the write and store operation of the SRAM.
 Load = 1 data will be written to the SRAM cells.
 Load = 0 data will be stored(previously written data) in the SRAM cells.
4. Data : (7:0) Serial input of bit stream to load into the SRAM.
5. Output Pin: There will be a single output pin which will be the output port of the LUT block.

PROJECT DETAILS

Logic Family	Standard CMOS
Logic Function	NAND(A,B,C)

Design of SRAM Cell:

Static random-access memory (static RAM or SRAM) is a type of [random-access memory](#) (RAM) that uses [latching circuitry \(flip-flop\)](#) to store each bit. SRAM is [volatile memory](#); data is lost when power is removed. [4]

Here we will adopt the standard 6 transistor (6T) design of SRAM cell.

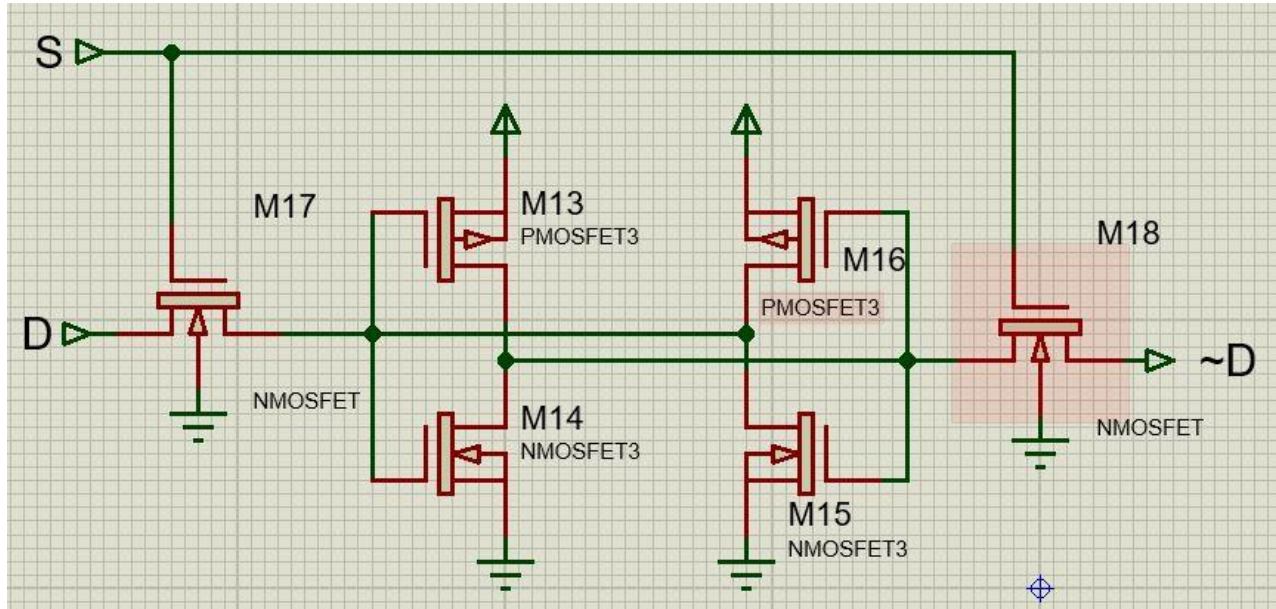


Fig 1: 6T SRAM Cell [4]

A typical SRAM cell is made up of six [MOSFETs](#). Each [bit](#) in an SRAM is stored on four [transistors](#) (M1, M2, M3, M4) that form two cross-coupled inverters. This storage cell has two stable states which are used to denote 0 and 1. Two additional access transistors serve to control the access to a storage cell during read and write operations. For our design, $S = \text{load pin}$.

$S = 1$; the write cycle begins by applying the value to be written to the bit lines $S = 0$; the read cycle is started.

$\sim D = \text{bit lines}$; through this line expected bit will be sent to the SRAM cell.

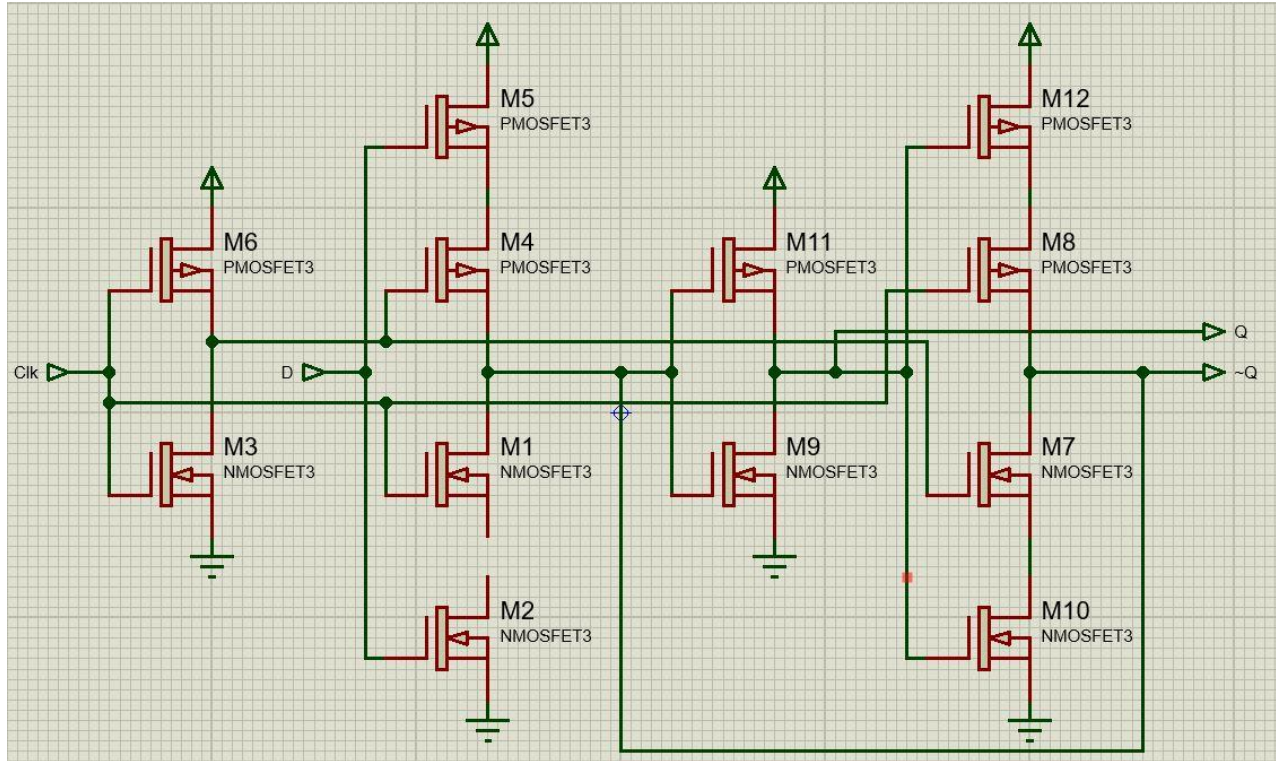
Schematic of D Flip-flop Using CMOS:

Fig 2: D flip-flop implemented using pass transistor

Here D = data input pin of the flip-flop

Clk :clock pin of the flip-flop.

Q = output pin of the flip-flop

~Q = inverted output of the flip-flop

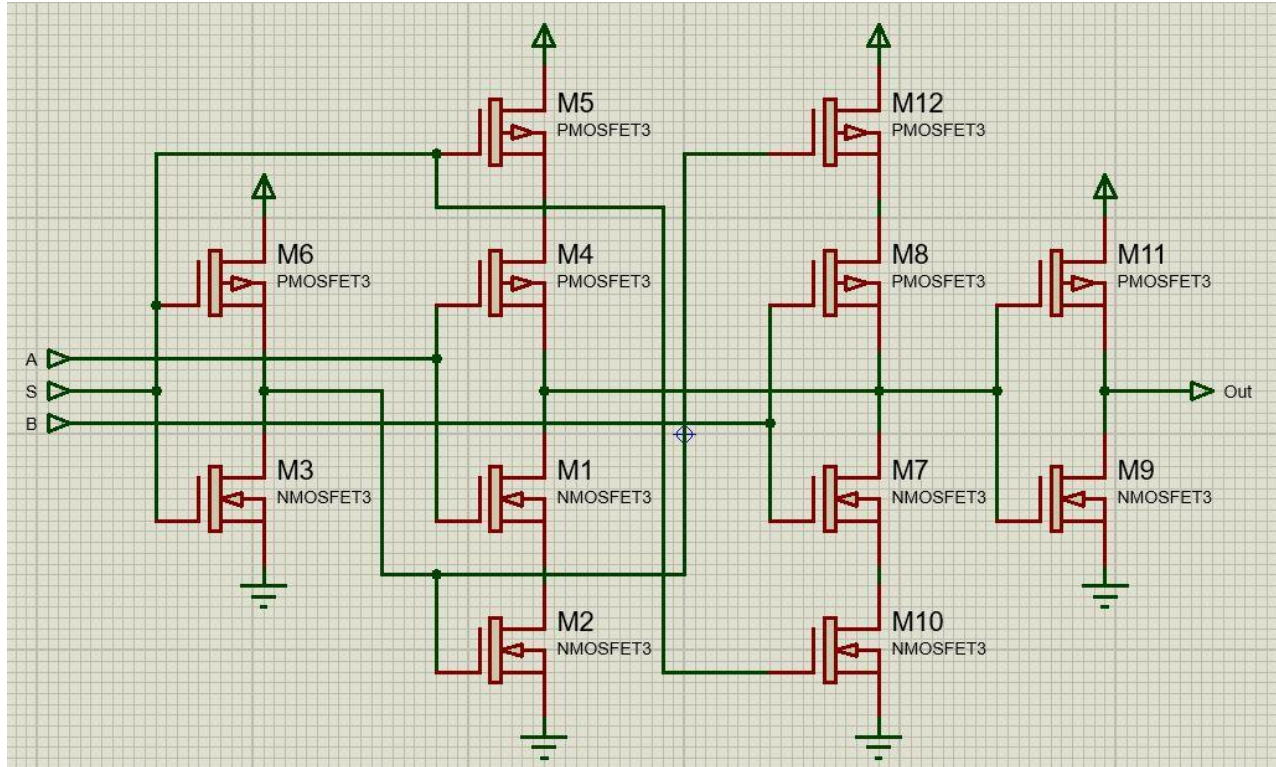
Schematic of Mux Using CMOS:

Fig 3: 2:1 mux using pass transistor.

Here S = Select pin of the mux

A & B = These are the input pins of the mux which will connect with Out based on the values of select pin. In our design A & B will come from two different SRAM cells.

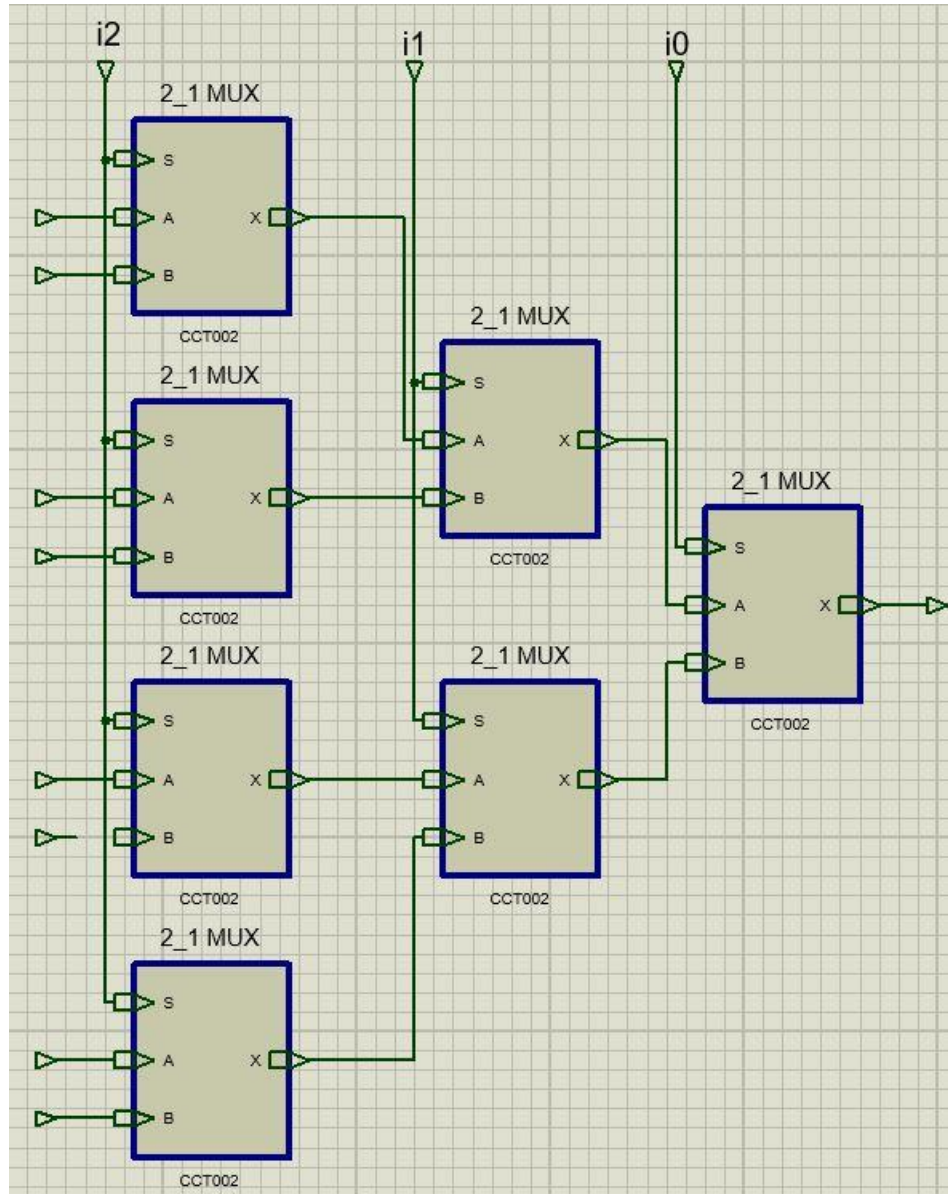
Schematic of LUT using the CMOS mux:

Fig 4 : 3:1 Look-up table

Here we will design the 2:1 mux using the pass transistor logic and the corresponding schematic is attached above. This will be basically an 8:1 mux which will be implemented with five 2:1 mux.

WORK DIVISION

Members Name	Assigned Work
Shakil Ahmed(1606140)	1, 2, 3
Ishraq Tashdid(1606142)	4, 5, 6
Arnob Roy Shaon(1506093)	7, 8

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- [4] "FPGAKey," [Online]. Available: <https://www.fpgakey.com/wiki/details/51>.